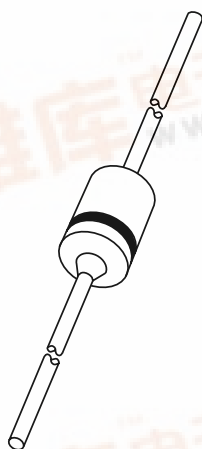


DISCRETE SEMICONDUCTORS

DATA SHEET



BYD33 series Fast soft-recovery controlled avalanche rectifiers

Product specification
Supersedes data of 1996 Jun 05

1996 Sep 18

Fast soft-recovery controlled avalanche rectifiers

BYD33 series

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

DESCRIPTION

Cavity free cylindrical glass package through Implotec™⁽¹⁾ technology. This package is hermetically sealed

and fatigue free as coefficients of expansion of all used parts are matched.

(1) Implotec is a trademark of Philips.

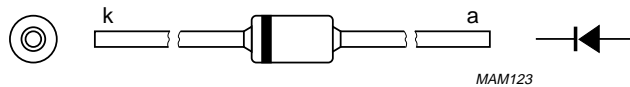


Fig.1 Simplified outline (SOD81) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage				
	BYD33D		—	200	V
	BYD33G		—	400	V
	BYD33J		—	600	V
	BYD33K		—	800	V
	BYD33M		—	1000	V
	BYD33U		—	1200	V
	BYD33V		—	1400	V
V_R	continuous reverse voltage				
	BYD33D		—	200	V
	BYD33G		—	400	V
	BYD33J		—	600	V
	BYD33K		—	800	V
	BYD33M		—	1000	V
	BYD33U		—	1200	V
	BYD33V		—	1400	V
$I_{F(AV)}$	average forward current	$T_{tp} = 55\text{ °C}$; lead length = 10 mm; see Figs 2 and 3;			
	BYD33D to M	averaged over any 20 ms period; see also Figs 10 and 11	—	1.30	A
	BYD33U and V		—	1.26	A
$I_{F(AV)}$	average forward current	$T_{amb} = 65\text{ °C}$; PCB mounting (see Fig.19); see Figs 4 and 5;			
	BYD33D to M	averaged over any 20 ms period; see also Figs 10 and 11	—	0.70	A
	BYD33U and V		—	0.67	A
I_{FRM}	repetitive peak forward current	$T_{tp} = 55\text{ °C}$; see Figs 6 and 7			
	BYD33D to M		—	12	A
	BYD33U and V		—	11	A

Fast soft-recovery controlled avalanche rectifiers

BYD33 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{FRM}	repetitive peak forward current BYD33D to M BYD33U and V	$T_{amb} = 65\text{ }^{\circ}\text{C}$; see Figs 8 and 9	–	7	A
			–	6	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{j\text{ max}}$ prior to surge; $V_R = V_{RRM\text{ max}}$	–	20	A
E_{RSM}	non-repetitive peak reverse avalanche energy BYD33D to J BYD33K to V	$L = 120\text{ mH}$; $T_j = T_{j\text{ max}}$ prior to surge; inductive load switched off	–	10	mJ
			–	7	mJ
T_{stg}	storage temperature		–65	+175	$^{\circ}\text{C}$
T_j	junction temperature	see Figs 12 and 13	–65	+175	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 1\text{ A}$; $T_j = T_{j\text{ max}}$; see Figs 14 and 15	–	–	1.1	V
		$I_F = 1\text{ A}$; see Figs 14 and 15	–	–	1.3	V
$V_{(BR)R}$	reverse avalanche breakdown voltage BYD33D BYD33G BYD33J BYD33K BYD33M BYD33U BYD33V	$I_R = 0.1\text{ mA}$				
			300	–	–	V
			500	–	–	V
			700	–	–	V
			900	–	–	V
			1100	–	–	V
			1300	–	–	V
			1500	–	–	V
I_R	reverse current	$V_R = V_{RRM\text{ max}}$; see Fig.16	–	–	1	μA
		$V_R = V_{RRM\text{ max}}$; $T_j = 165\text{ }^{\circ}\text{C}$; see Fig.16	–	–	100	μA
t_{rr}	reverse recovery time BYD33D to J BYD33K and M BYD33U and V	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$ see Fig.21	–	–	250	ns
			–	–	300	ns
			–	–	500	ns
C_d	diode capacitance	$f = 1\text{ MHz}$; $V_R = 0\text{ V}$; see Figs 17 and 18	–	20	–	pF

Fast soft-recovery controlled avalanche rectifiers

BYD33 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\left \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current BYD33D to J BYD33K to V	when switched from $I_F = 1$ A to $V_R \geq 30$ V and $dI_F/dt = -1$ A/ μ s; see Fig.20	—	—	6	A/ μ s
			—	—	5	A/ μ s

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	60	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	120	K/W

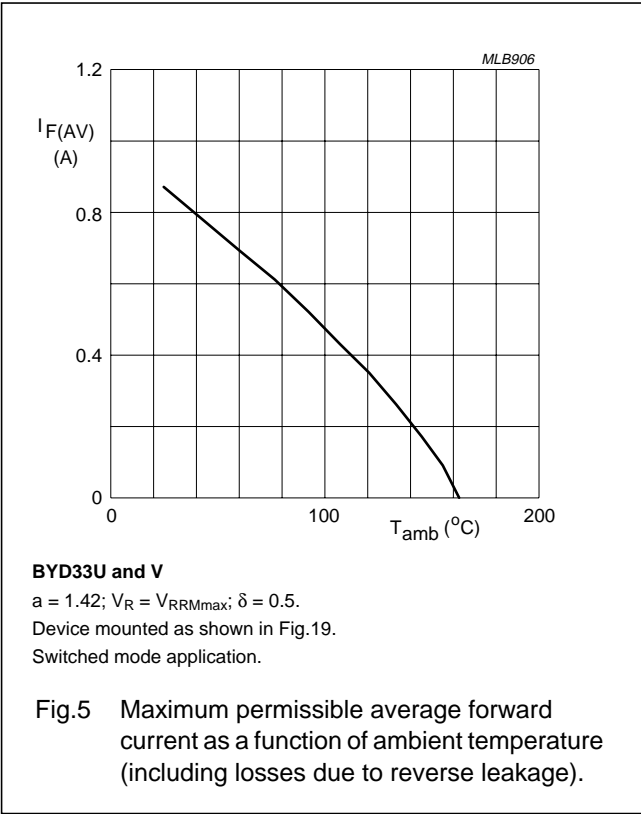
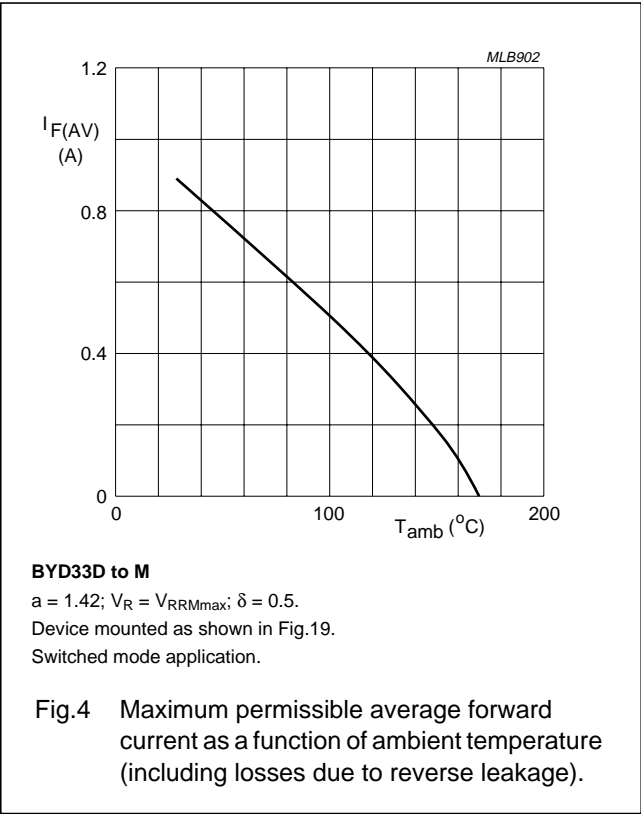
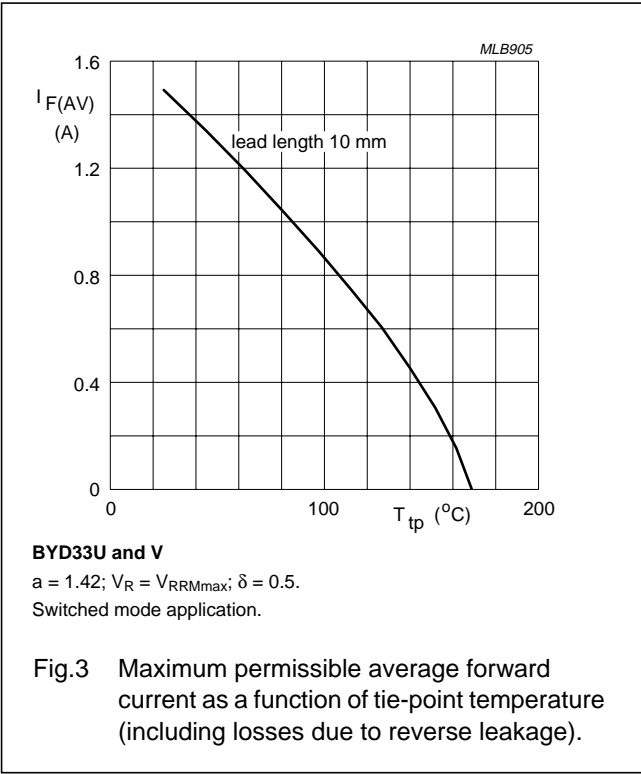
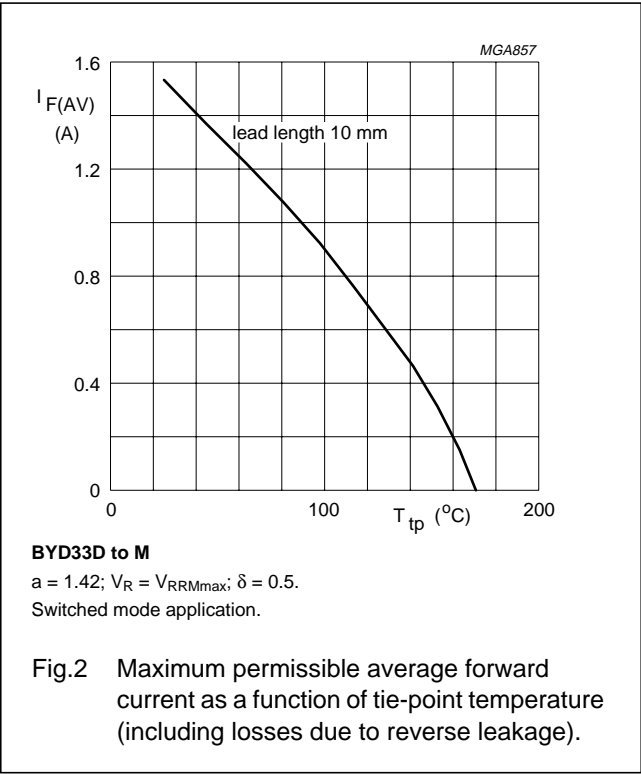
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥ 40 μ m, see Fig.19. For more information please refer to the "General Part of associated Handbook".

Fast soft-recovery
controlled avalanche rectifiers

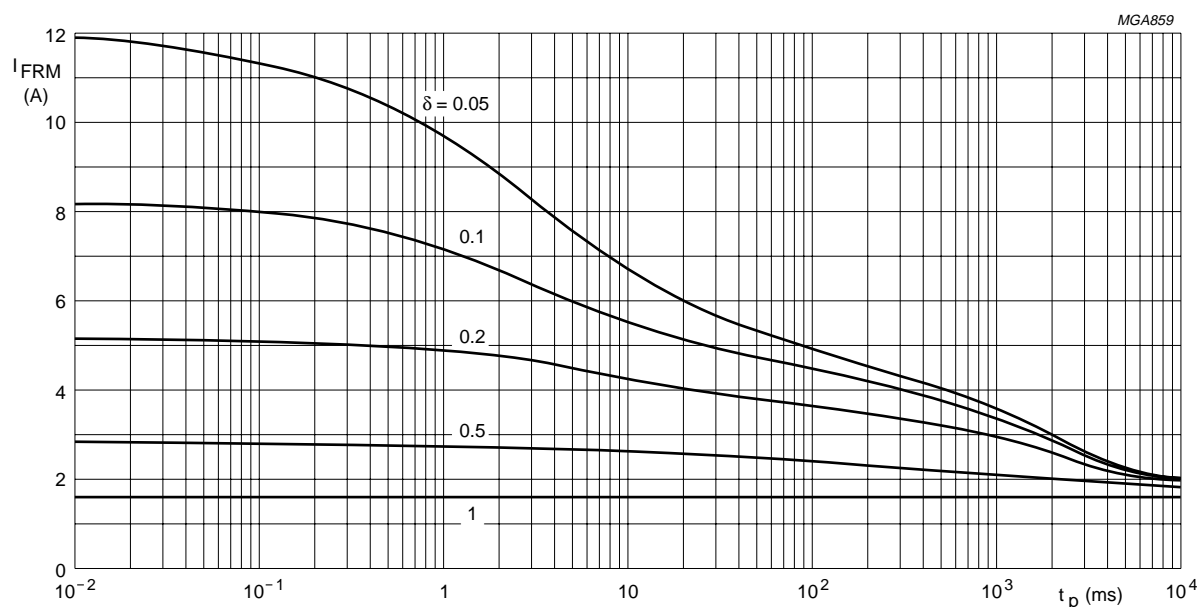
BYD33 series

GRAPHICAL DATA



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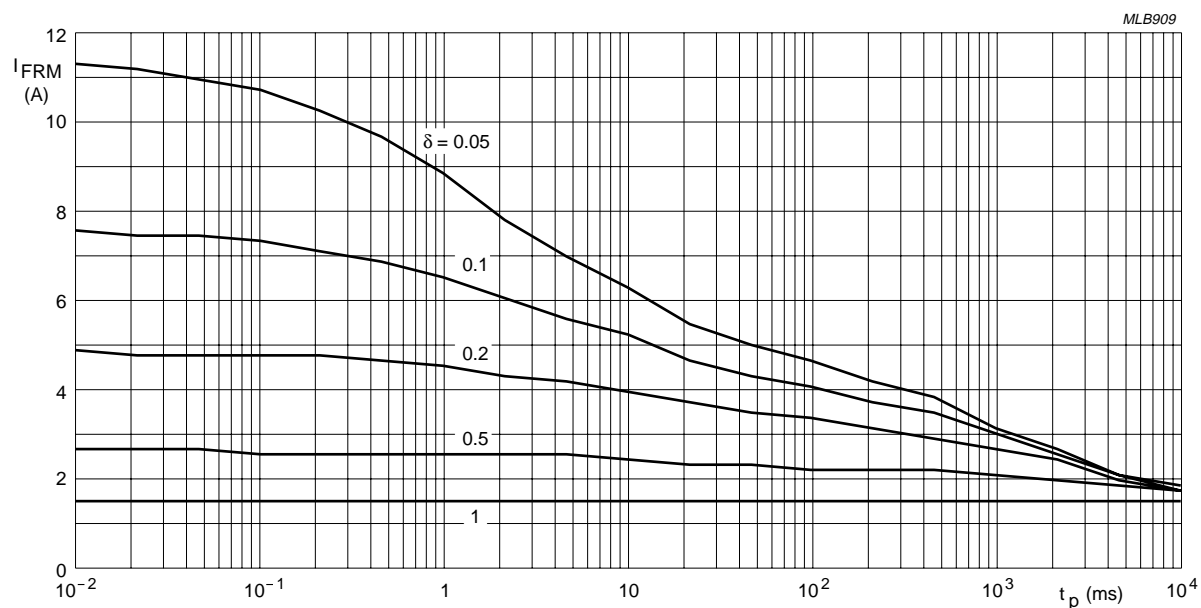


BYD33D to M

$T_{ip} = 55^\circ\text{C}$; $R_{th\ j-tp} = 60\text{ K/W}$.

V_{RRMmax} during $1 - \delta$; curves include derating for T_{jmax} at $V_{RRM} = 1000\text{ V}$.

Fig.6 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.



BYD33U and V

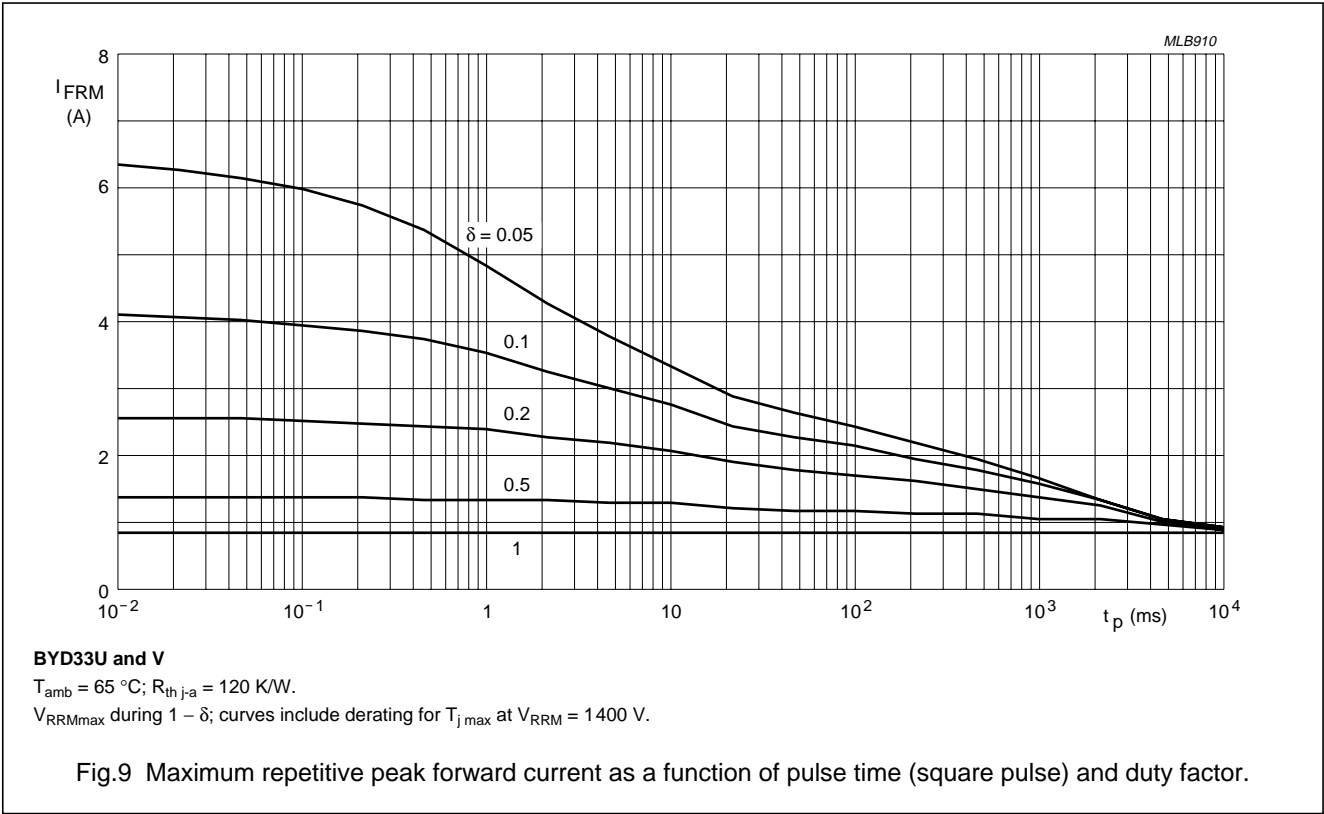
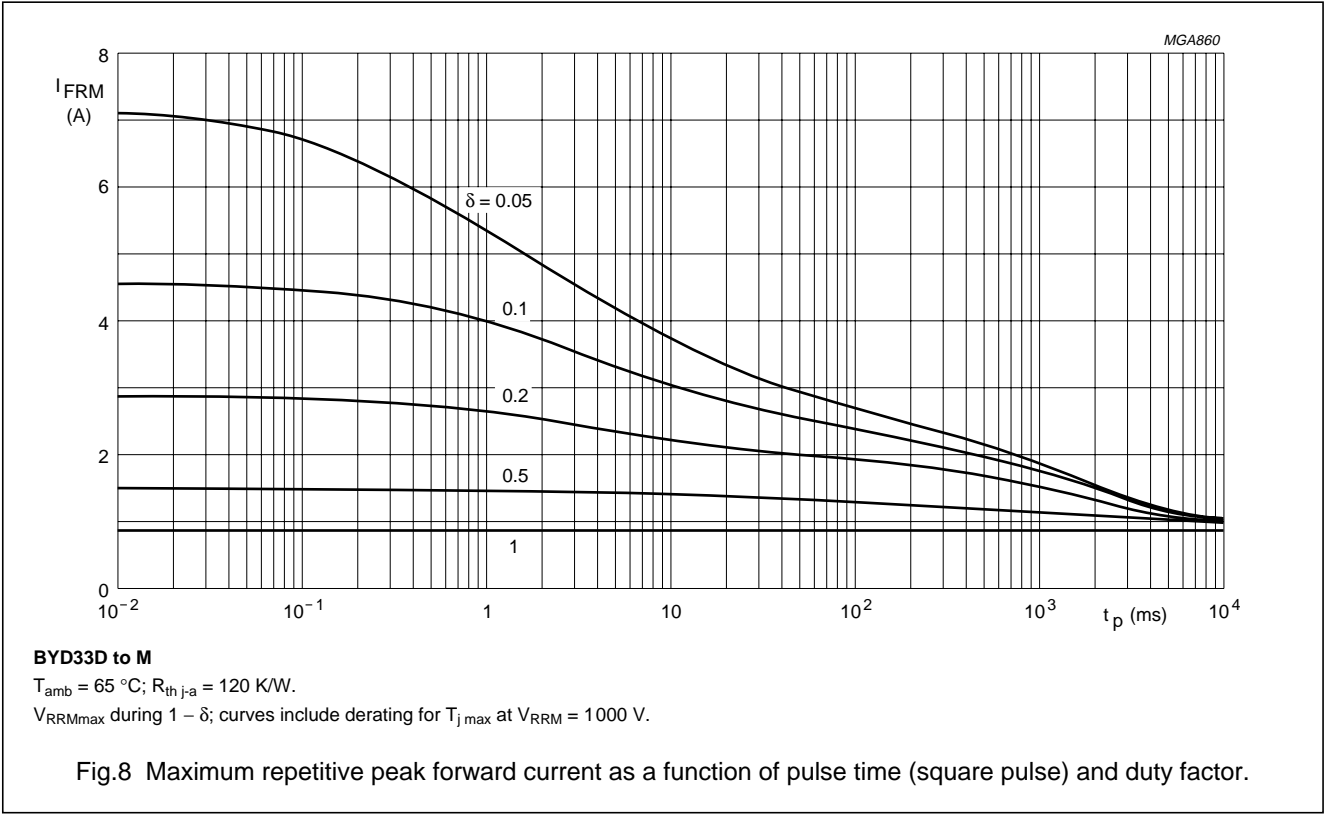
$T_{ip} = 55^\circ\text{C}$; $R_{th\ j-tp} = 60\text{ K/W}$.

V_{RRMmax} during $1 - \delta$; curves include derating for T_{jmax} at $V_{RRM} = 1400\text{ V}$.

Fig.7 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

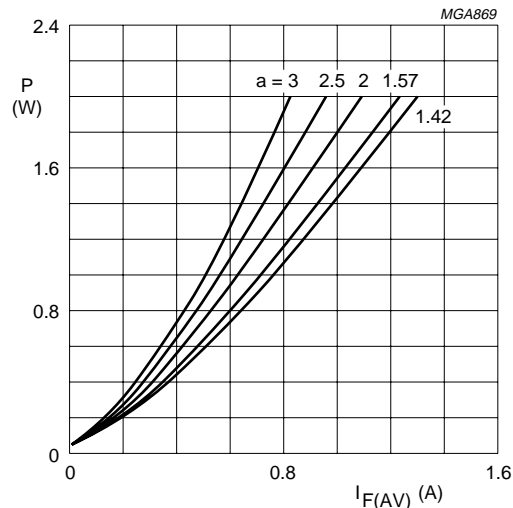
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controlled avalanche rectifiers

BYD33 series



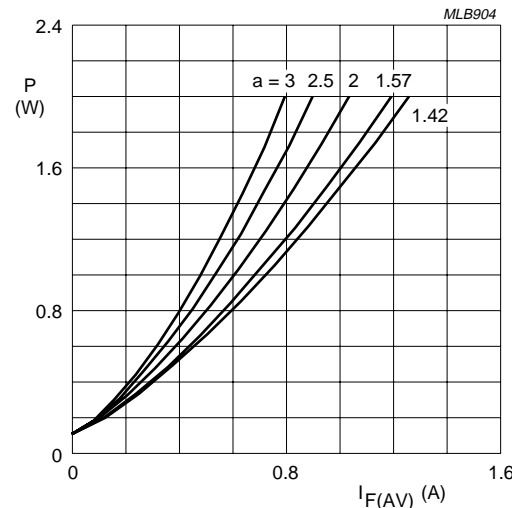
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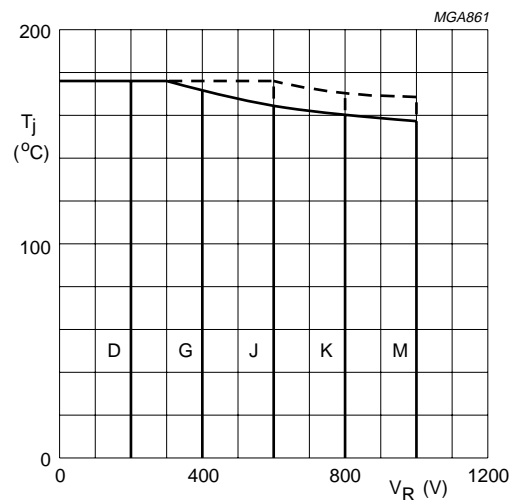
BYD33D to M
 $a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

Fig.10 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



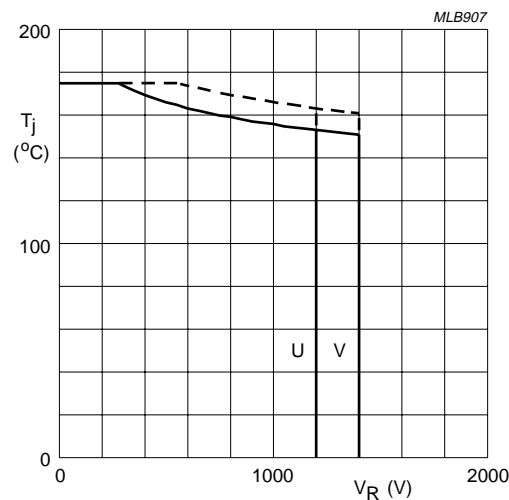
BYD33U and V
 $a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

Fig.11 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



BYD33D to M
Solid line = V_R .
Dotted line = V_{RRM} ; $\delta = 0.5$.

Fig.12 Maximum permissible junction temperature as a function of reverse voltage.

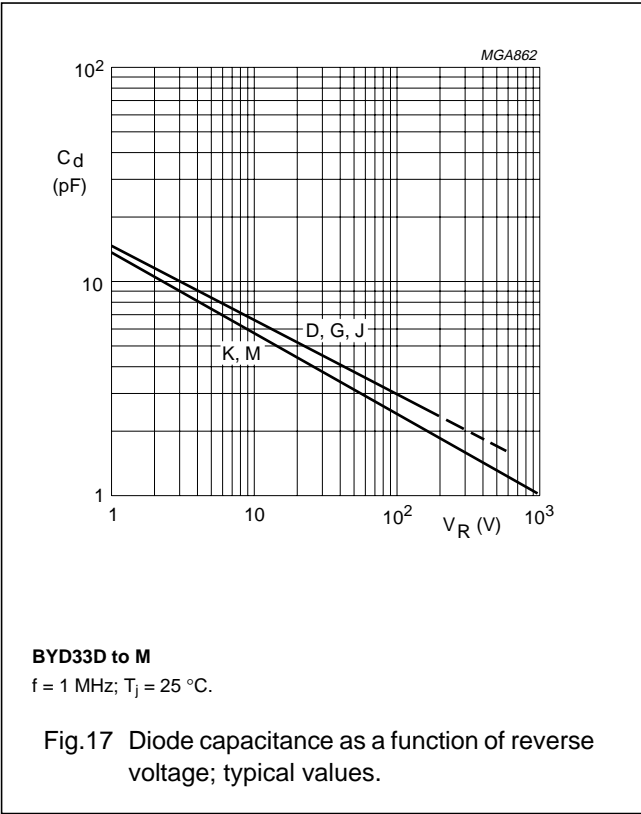
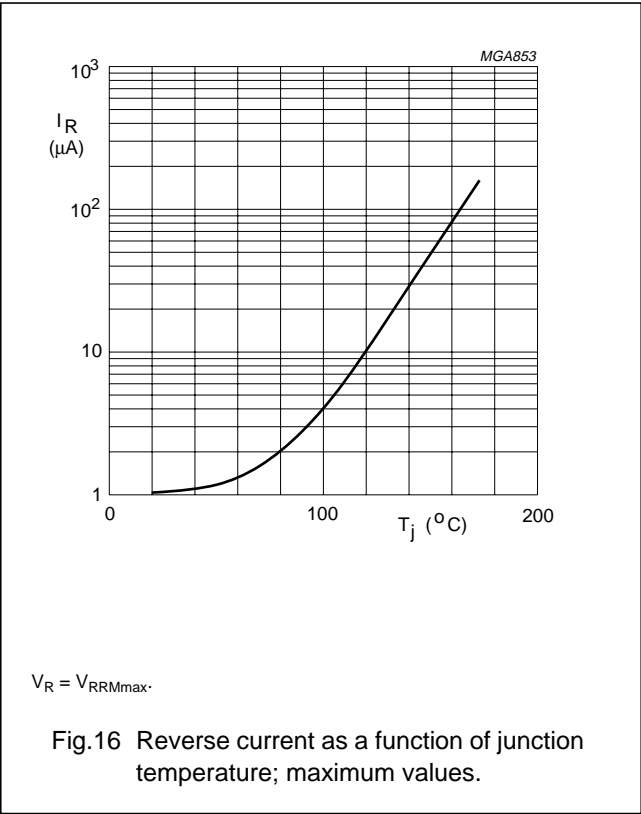
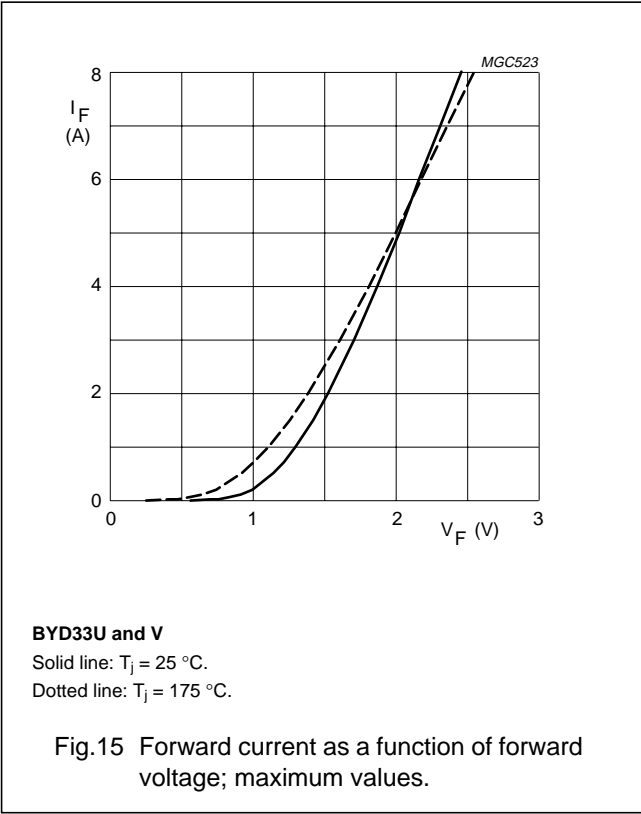
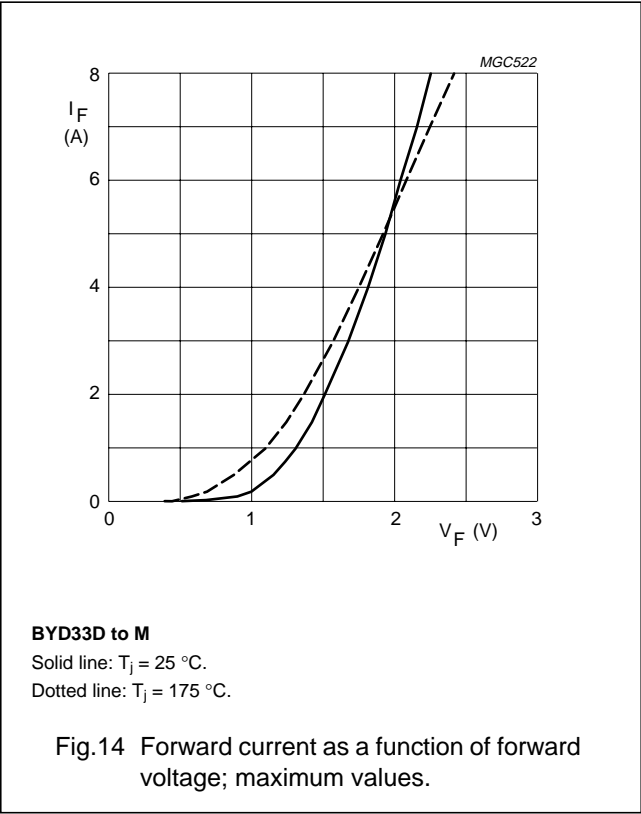


BYD33U and V
Solid line = V_R .
Dotted line = V_{RRM} ; $\delta = 0.5$.

Fig.13 Maximum permissible junction temperature as a function of reverse voltage.

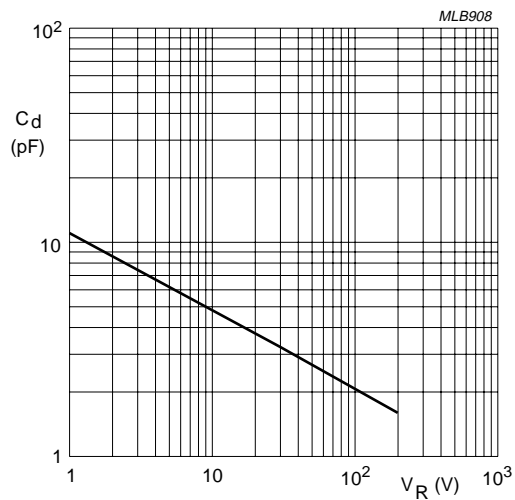
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controlled avalanche rectifiers

BYD33 series



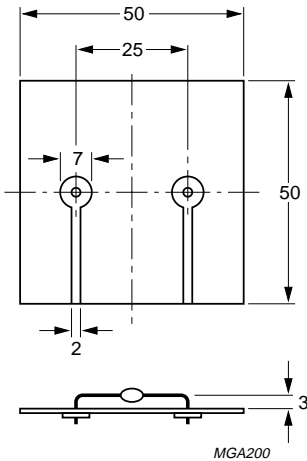
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BYD33U and V
 $f = 1\text{ MHz}$; $T_j = 25\text{ }^\circ\text{C}$.

Fig.18 Diode capacitance as a function of reverse voltage; typical values.



Dimensions in mm.

Fig.19 Device mounted on a printed-circuit board.

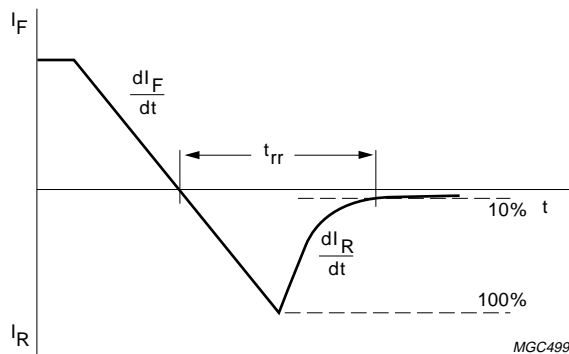
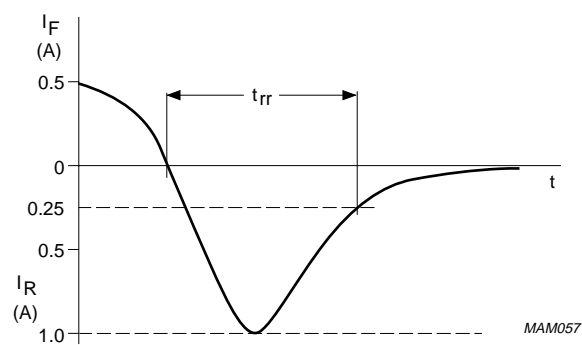
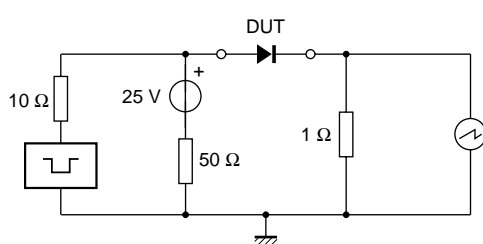


Fig.20 Reverse recovery definitions.

Fast soft-recovery controlled avalanche rectifiers

BYD33 series



Input impedance oscilloscope: 1 M Ω , 22 pF; $t_r \leq 7$ ns.

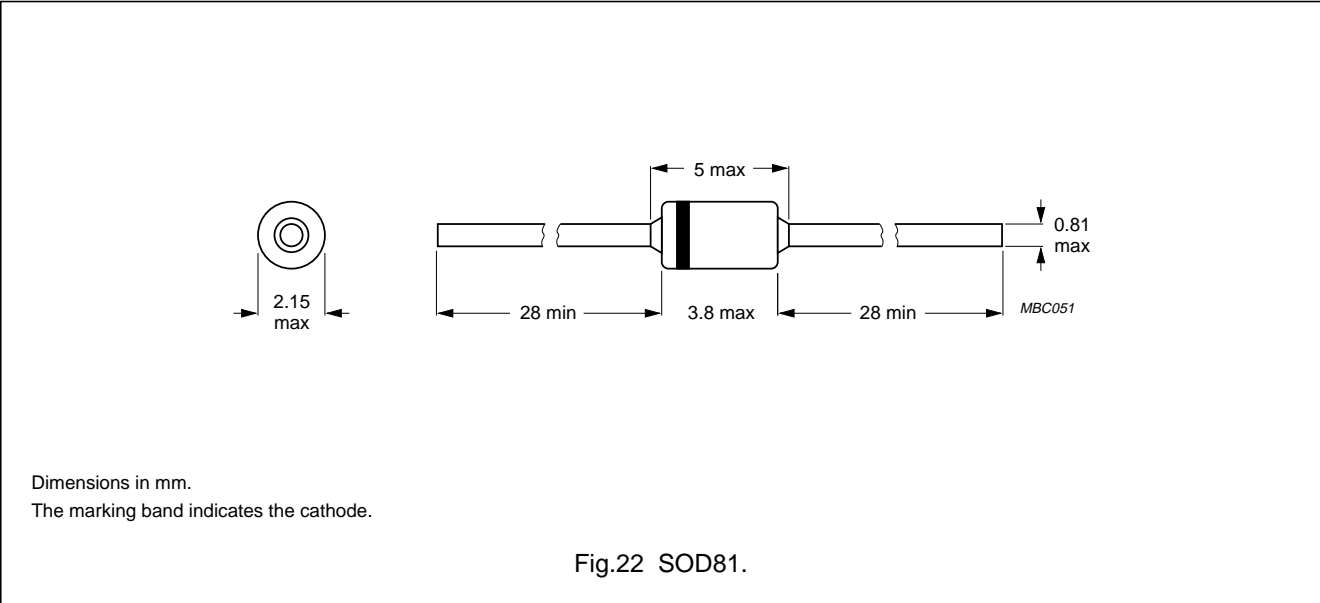
Source impedance: 50 Ω ; $t_r \leq 15$ ns.

Fig.21 Test circuit and reverse recovery time waveform and definition.

Fast soft-recovery
controlled avalanche rectifiers

BYD33 series

PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.